

High Speed Dual MOSFET Driver

Features

- 6ns rise and fall time with 1000pF load
- 2.0A peak output source/sink current
- 1.2V to 5.0V input CMOS compatible
- 4.5V to 13V single positive supply voltage
- Smartlogic threshold
- Low jitter design
- Two matched channels
- Outputs can swing below ground
- Low inductance package
- Thermally-enhanced package

Applications

- Medical ultrasound imaging
- Piezoelectric transducer drivers
- Non-Destructive Testing (NDT)
- PIN diode driver
- CCD clock driver/buffer
- High speed level translator

General Description

The Supertex MD1210 is a high speed, dual MOSFET driver. It is designed to drive high voltage P and N-channel MOSFET transistors for medical ultrasound and other applications requiring a high output current for a capacitive load. The high-speed input stage of the MD1210 can operate from 1.2V to 5.0V logic interface with an optimum operating input signal range of 1.8V to 3.3V. An adaptive threshold circuit is used to set the level translator switch threshold to the average of the input logic 0 and logic 1 levels. The input logic levels may be ground referenced, even though the driver is putting out bipolar signals. The level translator uses a proprietary circuit, which provides DC coupling together with high-speed operation.

 V_{DD} 1, V_{DD} 2, and VH should be connected to the positive supply voltage, and V_{SS} 1, V_{SS} 2, and VL should be connected to 0V or to Ground. The GND pin is the logic control input signal digital ground. The output stage is capable of peak currents of up to ±2.0A, depending on the supply voltages used and load capacitance present.

The OE pin serves a dual purpose. First, its logic H level is used to compute the threshold voltage level for the channel input level translators. Secondly, when OE is low, the outputs are disabled, with the A output high and the B output low. This assists in properly precharging the AC coupling capacitors that may be used in series in the gate drive circuit of an external PMOS and NMOS transistor pair.



Typical Application Circuit

Ordering Information

	Package
Device	12-Lead QFN 4.00x4.00mm body 1.00mm height (max) 0.80mm pitch
MD1210	MD1210K6-G

-G indicates package is RoHS compliant ('Green')

Absolute Maximum Ratings

Parameter	Value				
$V_{DD}^{}$ 1, $V_{DD}^{}$ 2, $V_{H}^{}$ - supply voltage	-0.5V to +13.5V				
$V_{ss}^{}$ 1, $V_{ss}^{}$ 2, $V_{L}^{}$ - supply voltage	0V				
Logic input levels	-0.5V to 7.0V				
Maximum junction temperature	+125°C				
Storage temperature	-65°C to 150°C				
Operating temperature	-20°C to 85°C				

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.



Pin Configuration



• 1210 YWLL

Y = Last Digit of Year Sealed W = Code for Week Sealed L = Lot Number _____ = "Green" Packaging

Package may or may not include the following marks: Si or 🎲

12-Lead QFN (K6)

DC Electrical Characteristics

(Over operating conditions unless otherwise specified, $V_H = V_{DD1} = V_{DD2} = 12V$, $V_L = V_{SS1} = V_{SS2} = 0V$, $V_{OE} = 3.3V$, $T_A = 25^{\circ}C$)

Sym		Min	Тур	Max	UL	Conditions
$V_{DD}1, V_{DD}2$	Supply voltage	4.5	-	13	V	
V _H	Output high supply voltage	V _{ss} +2.0	-	V _{DD}	V	
V _L	Output low supply voltage	0	-	V _{DD} -2.0	V	
I _{DD} 1Q	V _{DD} 1 quiescent current	-	0.55	-	mA	
I _{DD} 2Q	V _{DD} 2 quiescent current	-	-	10	μA	No input transitions
I _{HQ}	V _H quiescent current	-	-	10	μA	
I _{DD} 1	V _{DD} 1 average current	-	0.88	-	mA	
I _{DD} 2	V _{DD} 2 average current	-	6.6	-	mA	One channel on at 5.0Mhz, No load
I _H	V _H average current	-	23	-	mA	
V _{IH}	Input logic voltage high	V _{OE} -0.3	-	5.0	V	
V _{IL}	Input logic voltage low	0	-	0.3	V	For logic inputs INA and IND
I _{IH}	Input logic current high	-	-	1.0	μA	For logic inputs INA and INB
I	Input logic current low	-	-	1.0	μA	

DC Electrical Characteristics (cont.) (Over operating conditions unless otherwise specified, $V_H = V_{DD1} = V_{DD2} = 12V$, $V_L = V_{SS1} = V_{SS2} = 0V$, $V_{OE} = 3.3V$, $T_A = 25^{\circ}C$)

(010) 000100		DD1 DD2	1 2 •, •	SS1 SS2	OF, OE	5.51, T _A 20 0)
Sym	Parameter	Min	Тур	Max	Units	Conditions
V _{IH}	OE Input logic voltage high	1.2	-	5.0	V	
V	OE Input logic voltage low	0	-	0.3	V	For logic input OE
R _{IN}	OE input logic impedance to GND	12	20	30	KΩ	
C	Logic input capacitance	-	5.0	10	pF	All inputs
$\theta_{_{JA}}$	Thermal resistance to air	-	47	-	°C/W	1oz. 4-layer 3x4" PCB with thermal pad and thermal via array
$\theta^{\rm JC}$	Thermal resistance to case	-	7.0	-	°C/W	

Outputs $(V_{H} = V_{DD1} = V_{DD2} = 12V, V_{L} = V_{SS1} = V_{SS2} = 0V, V_{OE} = 3.3V, T_{A} = 25^{\circ}C)$

Sym	Parameter	Min	Тур	Max	Units	Conditions
R _{SINK}	Output sink resistance	-	-	12.5	Ω	I _{SINK} = 50mA
R _{SOURCE}	Output source resistance	-	-	12.5	Ω	I _{SOURCE} = 50mA
I _{SINK}	Peak output sink current	-	2.0	-	A	
	Peak output source current	-	2.0	-	Α	

AC Electrical Characteristics ($V_{H} = V_{DD1} = V_{DD2} = 12V$, $V_{L} = V_{SS1} = V_{SS2} = 0V$, $V_{OE} = 3.3V$, $T_{A} = 25^{\circ}C$)

Sym	Parameter	Min	Тур	Max	Units	Conditions
t _{irf}	Inputs or OE rise & fall time	-	-	10	ns	Logic input edge speed require- ment
t _{PLH}	Propagation delay when output is from low to high	-	7.0	-	ns	
t _{PHL}	Propagation delay when output is from high to low	-	7.0	-	ns	C _{LOAD} = 1000pF, see timing diagram
t _{POE}	Propagation delay OE to outputs	-	9.0	-	ns	Input signal rise/fall time of 2ns
t,	Output rise time	-	6.0	-	ns	
t,	Output fall time	-	6.0	-	ns	
lt _r - t _f l	Rise and fall time matching	-	1.0	-	ns	
I t _{PLH} -t _{PHL} I	Propagation low to high and high to low matching	-	1.0	-	ns	For each channel
∆t _{dm}	Propagation delay match	_	±2.0	-	ns	Device to device delay match

Logic Truth Table

	Logic Inputs	Output				
OE	INA	INB	OUTA	OUTB		
Н	L	L	V _H	V _H		
Н	L	Н	V _H	VL		
Н	Н	L	VL	V _H		
Н	Н	Н	VL	VL		
L	Х	X	V _H	VL		

Timing Diagram



Propagation Delay



Detailed Block Diagram

Simplified Block Diagram



Logic Input Threshold





Application Information

For proper operation of the MD1210, low inductance bypass capacitors should be used on the various supply pins. The GND input pin should be connected to the digital ground. The INA, INB, and OE pins should be connected to their logic source with a swing of GND to logic level high, which is 1.2 to 5.0V. Good trace practices should be followed corresponding to the desired operating speed. The internal circuitry of the MD1210 is capable of operating up to 100MHz, with the primary speed limitation being the loading effects of the load capacitance. Because of this speed and the high transient currents that result with capacitive loads, the bypass capacitors should be as close to the chip pins as possible. The VSS1, VSS2, and VL pins should have low inductance feed-through connections directly to a ground plane. The power connections VDD1 and VDD2 should have a ceramic bypass capacitor to the ground plane with short leads and decoupling components to prevent resonance in the power leads. A common capacitor and voltage source may be used for these two pins, which should always have the same DC voltage applied. For applications sensitive to jitter and noise, separate decoupling networks may be used for VDD1 and VDD2.

The VH and VL pins can draw fast transient currents of up to 2.0A, so they should be provided with an appropriate bypass capacitor located next to the chip pins. A ceramic capacitor of up to 1.0µF may be appropriate, with a series ferrite bead to prevent resonance in the power supply lead coming to the capacitor. Pay particular attention to minimizing trace lengths and using sufficient trace width to reduce inductance. Surface mount components are highly recommended. Since the output impedance of this driver is very low, in some cases it may be desirable to add a small series resistor in series with the output signal to obtain better waveform integrity at the load terminals. This will of course reduce the output voltage slew rate at the terminals of a capacitive load.

Pay particular attention to the parasitic coupling from the driver output to the input signal terminals. This feedback may cause oscillations or spurious waveform shapes on the edges of signal transitions. Since the input operates with signals down to 1.2V even small coupled voltages may cause problems. Use of a solid ground plane and good power and signal layout practices will prevent this problem. Be careful that the circulating ground return current from a capacitive load cannot react with common inductance to cause noise voltages in the input logic circuitry.

Descr	iption
Name	Description
INA	Logic input. Controls OUTA when OE is high. Input logic high will cause the output to swing to VL. Input logic low will cause the output to swing to VH.
VL	Supply voltage for N-channel output stage.
INB	Logic input. Controls OUTB when OE is high. Input logic high will cause the output to swing to VL. Input logic low will cause the output to swing to VH.
GND	Logic input ground reference.
V _{ss} 1	Low side analog circuit and level shifter supply voltage. Should be at the same potential as V_{ss}^2 .
V _{ss} 2	Low side gate drive supply voltage.
OUTB	Output driver. Swings from VH to VL. Intended to drive the gate of an external N-channel MOSFET via a series capacitor. When OE is low, the output is disabled. OUTB will swing to VL turning off the external N-channel MOSFET.
VH	Supply voltage for P-channel output stage.
OUTA	Output driver. Swings from VH to VL. Intended to drive the gate of an external P-channel MOSFET via a series capacitor. When OE is low, the output is disabled. OUTA will swing to VH turning off the external P-channel MOSFET.
V _{DD} 2	High side gate drive supply voltage.
V_{DD} 1	High side analog circuit and level shifter supply voltage. Should be at the same potential as V_{DD}^2 .
OE	Output-enable logic input. When OE is high, $(V_{OE} + V_{GND})/2$ sets the threshold transition between logic level high and low for INA and INB. When OE is low, OUTA is at VH and OUTB is at VL regardless of INA and INB.
	Name INA VL INB GND Vss1 Vss2 OUTB VH OUTA VD2 VD2 VD2 VD1

Deceriptic:

Notes: 1

Thermal Pad and Pin #5 (V_{ss} 1) must be connected externally.

Index Pad and Thermal Pad are connected internally 2.

12-Lead QFN Package Outline (K6) 4.00x4.00mm body, 1.00mm height (max), 0.80mm pitch



Notes:

- 2. Depending on the method of manufacturing, a maximum of 0.15mm pullback (L1) may be present.
- 3. The inner tip of the lead may be either rounded or square.

Symb	ol	Α	A1	A3	b	D	D2	E	E2	е	L	L1	θ
	MIN	0.80	0.00		0.25	3.85*	0.75	3.85*	0.75		0.35	0.00	0 0
Dimension (mm)	NOM	0.90	0.02	0.20 REF	0.30	4.00	1.70	4.00	1.70	0.80 BSC	0.55	-	-
()	MAX	1.00	0.05		0.35	4.15*	2.25	4.15*	2.25	200	0.75	0.15	14 ⁰

JEDEC Registration MO-220, Variation VGGB, Issue K, June 2006.

* This dimension is not specified in the JEDEC drawing.

Drawings not to scale.

Supertex Doc. #: DSPD-12QFNK64X4P080, Version C041309.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <u>http://www.supertex.com/packaging.html</u>.)

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^{1.} A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.